

January 7, 1998

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AXIAL LEADED HERMETICALLY SEALED SUPERFAST RECTIFIER DIODE

QUICK REFERENCE DATA

- Very low reverse recovery time
- Glass passivated for hermetic sealing
- Low switching losses
- Soft, non-snap off, recovery characteristics
- Low forward voltage drop

- $V_R = 50 - 200V$
- $I_F = 2.6A$
- $t_{rr} = 25nS$
- $V_F = 0.97V$

ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	2PFT05	2PFT1	2PFT15	2PFT2	Unit
Working reverse voltage	V_{RWM}	50	100	150	200	V
Repetitive reverse voltage	V_{RRM}	50	100	150	200	V
Average forward current (@ 55°C, lead length = 0.375")	$I_{F(AV)}$	← 2.6 →				A
Repetitive surge current (@ 55°C in free air, lead length 0.375")	I_{FRM}	← 15.0 →				A
Non-repetitive surge current ($t_p = 8.3mS$, @ V_R & T_{jmax})	I_{FSM}	← 50.0 →				A
Storage temperature range	TSTG	← -65 to +175 →				°C
Operating temperature range	TOP	← -65 to +175 →				°C

MECHANICAL

G88

DIM #	DIMENSIONS				NOTE
	MM		INCHES		
A	-	3.81	-	.150	-
B	28.0	-	1.10	-	-
C	-	4.57	-	.180	-
D	-	0.81	-	.032	-

Weight = 0.013oz

These products are qualified in Europe to DEF STAN 59-61 (PART 80)/043 available to F and FX levels.

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ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

	Symbol	2PFT05	2PFT1	2PFT15	2PFT2	Unit
Average forward current max. (pcb mounted; T _A = 55°C) for sine wave	I _{F(AV)}	← 1.35 →				A
	I _{F(AV)}	← 1.40 →				A
Average forward current max. (T _L = 55°C ; L = 3/8") for sine wave	I _{F(AV)}	← 2.4 →				A
	I _{F(AV)}	← 2.6 →				A
I ² t for fusing (t = 8.3mS) max.	I ² t	← 10.6 →				A ² S
Forward voltage drop max. @ I _F = 2.0A, T _j = 25°C	V _F	← 0.97 →				V
Reverse current max. @ V _{RWM} , T _j = 25°C	I _R	← 1.0 →				μA
	I _R	← 10 →				μA
Reverse recovery time max. 0.5A I _F to 1.0A I _R . Recovers to 0.25A I _{RR} .	t _{rr}	← 25 →				nS
Junction capacitance typ. @ V _R = 5V, f = 1MHz	C _j	← 45 →				pF

THERMAL CHARACTERISTICS

	Symbol	2PFT05	2PFT1	2PFT15	2PFT2	Unit
Thermal resistance - junction to lead Lead length = 0.375"	R _{θJL}	← 47 →				°C/W
	R _{θJL}	← 19 →				°C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R _{θJA}	← 100 →				°C/W

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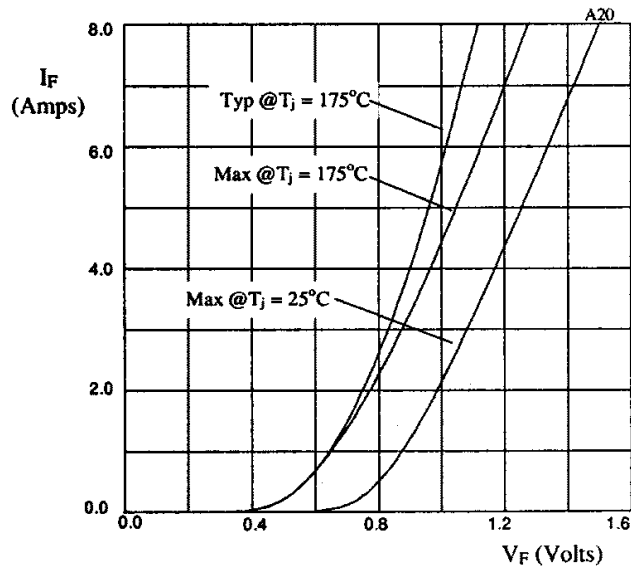


Fig 1. Forward voltage drops as a function of forward current.

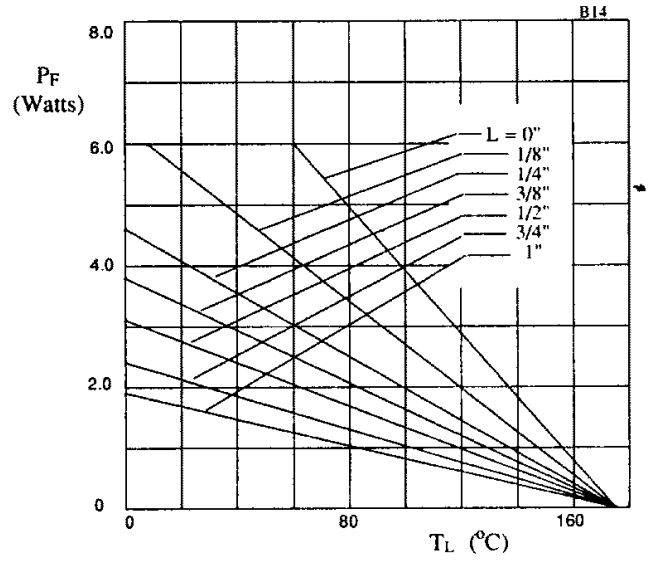


Fig 2. Maximum power versus lead temperature.

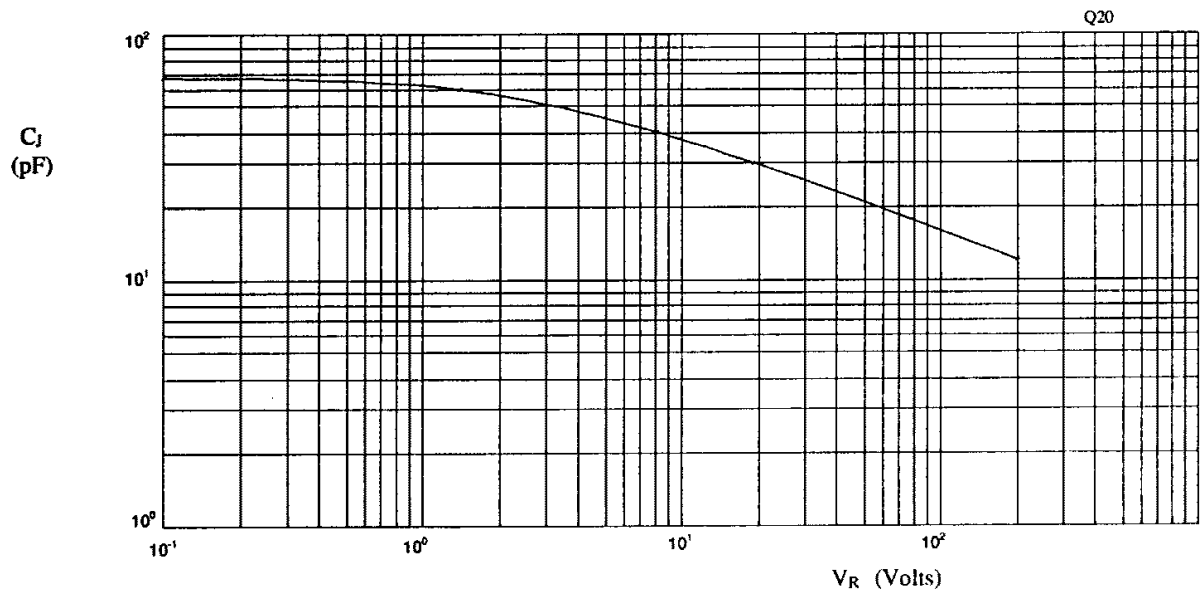


Fig 3. Typical junction capacitance as a function of reverse voltage.

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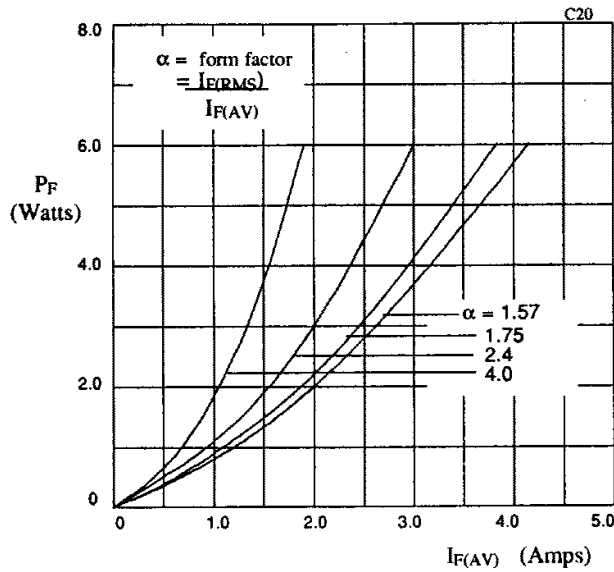


Fig 4. Forward power dissipation as a function of forward current, for sinusoidal operation.

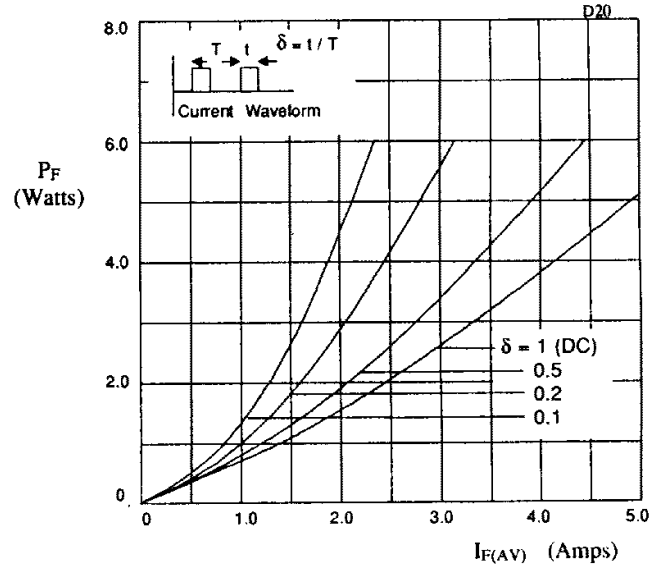


Fig 5. Forward power dissipation as a function of forward current, for square wave operation.

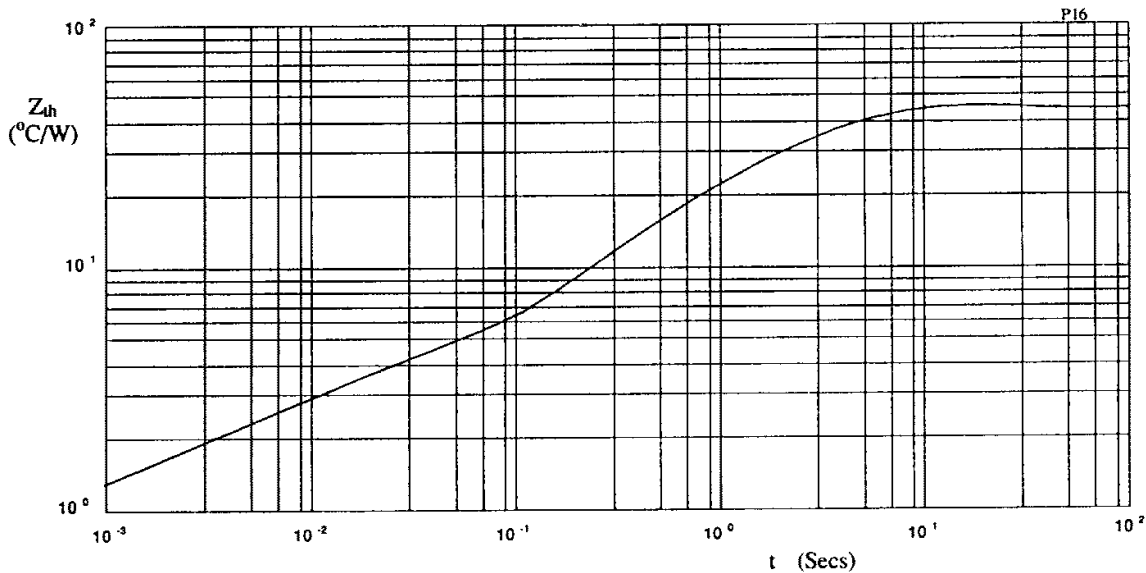


Fig 6. Transient thermal impedance characteristic.